BSI High Sensitivity UV Came



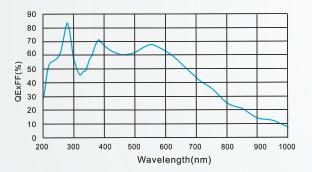
Applications

Semiconductor Fingerprint inspection Glass scratch inspection Corona detection

Advantages

Back-thinned CMOS Response from UV to NIR (180~1100nm) 83.3%@280nm Excellent UV imaging capability Very low readout noise: 1.3e-2048 x 2048 Resolution High dynamic range up to 93dB Multi trigger mode design USB3.0 transport interface

Quantum Efficiency



Specification

Product model	S-UV-M-R-U
Sensor type	BSICMOS
Resolution	2048x2048
Sensor size	2"
Color	Monochrome
Shutter type	Rolling Shutter
Pixel size	11µmx11µm
Quantum efficency	83.3%@280nm
Readout noise	1.3e-
Full well capacity	100ke-
Dynamic range	93dB
Frame rate	24fps
Bit depth	16bit
Analog gain	High/low gain
Exposure model	Auto, Manual, Trigger
Exposure time	0.02ms~10s
Image processing	Image Enhancement, Noise Reduction, Contrast, ROINoise Reductiomirror reversal, external trigger, gain, etc.
External trigger mode	Standard/synchronous/global/software trigger
Signal output	Exposure/readout/global
Optical interface	M42x0.75/C interface
Data interface	USB3.0
Power interface	USB3.0
Trigger interface	Hirose, HR10A-7R-6PB
Power supply	5V
Power consumption	<2.5 W
Size	351g,60mm x 60mm x 64.5mm
Operating temperature	-40°C~50°C

Indigo-Imaging Technology Co.,Ltd.

www.indigo-imaging.com

Tel: 0086-591-8358 8265-812Email: support@indigo-imaging.comAddress: BLD 5#, Intelligent Industry Park, 2#, YangQiZhi Road, Gaishan Town,CangShan District, FuZhou, CHINA